



**GP**  
**ELECTRONICS**

**SS52C-SS520C**

**20~200V-5A Schottky Rectifier**

### SS52C-SS520C Schottky Rectifier

#### Feature

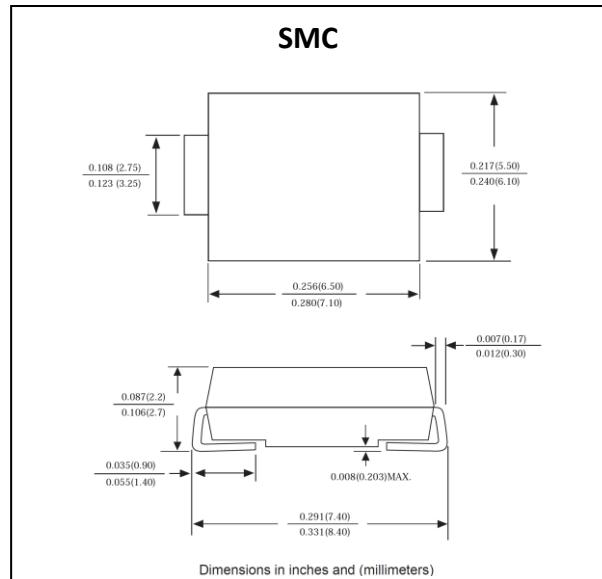
- High current capability
- Low VF
- High surge current capability

#### Application

- Rectifier

#### Marking

- SS5X
- X: From 2 To 20



### ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	SS5									Unit
		2	3	4	5	6	8	10	15	20	
Repetitive Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	80	100	150	200	V
Maximum RMS Voltage	$V_{RMS}$	14	21	28	35	42	56	70	105	140	V
Average Forward Current (60HZ Half-sine wave, Resistance load, TL(Fig.1))	$I_{F(AV)}$	5.0									A
Non-repetitive Peak Forward Surge Current (60Hz Half-sine wave ,1 cycle , $T_a=25^\circ\text{C}$ )	$I_{FSM}$	150									A
Junction Temperature	$T_J$	-55 ~ +125			-55 ~ +150						°C
Storage Temperature	$T_{STG}$	-55 ~ +150									°C

### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	SS5								Unit			
			2	3	4	5	6	8	10	15				
Peak Forward Voltage	$V_F$	$I_F = 1\text{A}$	0.55			0.70			0.85			V		
Peak Reverse Current	$I_{RRM1}$	$V_{RM}=V_{RRM}$	$T_a=25^\circ\text{C}$			0.5			0.2			mA		
	$I_{RRM2}$		$T_a=100^\circ\text{C}$			20			10			mA		
Thermal Resistance(Typical)	$R_{\theta J-A}$	Between junction and ambient	47								°C/W			
	$R_{\theta J-L}$		13									°C/W		

#### Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.60" x 0.60" (16.0 mm x 16.0 mm) copper pad areas

## Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

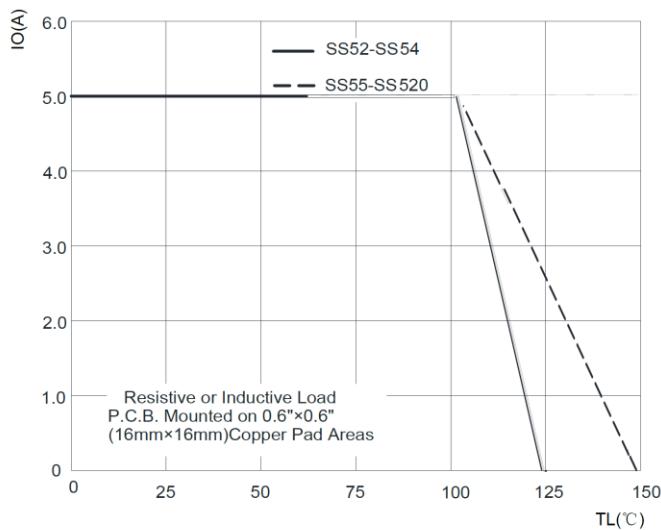


FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

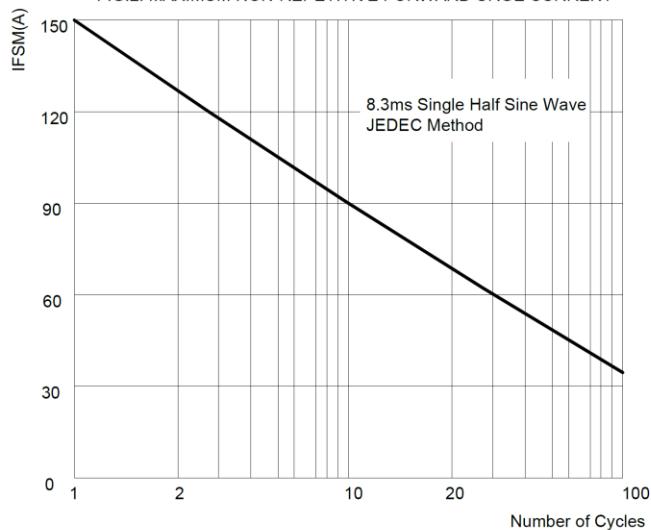


FIG.3: TYPICAL FORWARD CHARACTERISTICS

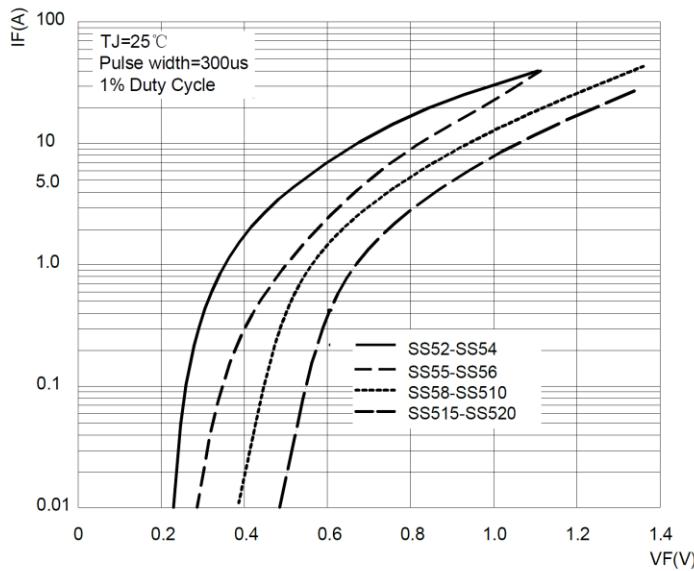


FIG.4: TYPICAL REVERSE CHARACTERISTICS

